



**DESCRIPTION**

The S10SC650VQ is available in TO-220-2 package.

V <sub>RRM</sub>	I <sub>F</sub>	Q <sub>c</sub>
650V	10A (TC=154°C )	30nC

**APPLICATION**

- Switch mode power supply
- Solar inverter
- Data Center
- Uninterruptible power supply

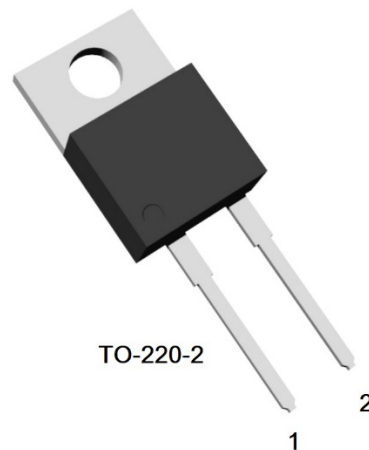
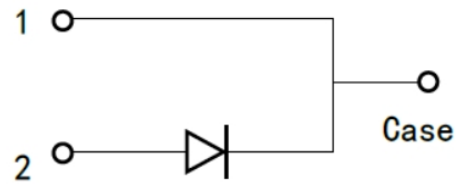
**ORDERING INFORMATION**

Package Type	Part Number
TO-220-2	S10SC650V
Note	SPQ: 50pcs/Tube
AiT provides all RoHS products	

**FEATURE**

- Negligible reverse recovery
- High-speed switching
- Positive Temperature Coefficient
- Temperature-Independent Switching
- High Frequency
- Low heat dissipation requirements
- Reduce size and cost of the system
- High-reliability

**PIN DESCRIPTION**



Pin	PIN DESCRIPTION
1	CATHODE
2	ANODE



## ABSOLUTE MAXIMUM RATINGS

T<sub>C</sub>=25°C , unless otherwise noted

V <sub>RRM</sub> , Repetitive peak reverse voltage		650V
I <sub>F</sub> , Continuous forward current	T <sub>C</sub> =25°C	32A
	T <sub>C</sub> =135°C	15A
	T <sub>C</sub> =154°C	10A
I <sub>FSM</sub> , Non-repetitive forward surge current see Fig 3.	T <sub>C</sub> =25°C, tp=10ms,Half sine pulse	96A
	T <sub>C</sub> =110°C, tp=10ms,Half sine pulse	83A
I <sub>FRM</sub> , Repetitive Peak Forward Surge Current	T <sub>C</sub> =25°C, tp=10ms,Half sine pulse	85A
∫ i <sup>2</sup> dt, i <sup>2</sup> t value	T <sub>C</sub> =25°C, tp=10ms	60.5A <sup>2</sup> S
	T <sub>C</sub> =110°C, tp=10ms	44 A <sup>2</sup> S
P <sub>tot</sub> , Power Dissipation, see Fig 4.	T <sub>C</sub> =25°C	127W
	T <sub>C</sub> =110°C	55 W
	T <sub>C</sub> =150°C	21 W
T <sub>J</sub> , T <sub>stg</sub> , Operating and Storage Temperature		-55°C~+175°C
R <sub>th(j-c)</sub> , Thermal resistance ( Junction to case ) , see Fig 8.		1.175°C/W

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

T<sub>C</sub> = 25°C, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
DC blocking voltage	V <sub>DC</sub>		650	-	-	V
Forward voltage, see Fig 1.	V <sub>F</sub>	I <sub>F</sub> =5A	-	1.17	-	V
		I <sub>F</sub> =10A, T <sub>C</sub> =25°C	-	1.37	1.6	V
		I <sub>F</sub> =10A, T <sub>C</sub> =175°C	-	1.66	-	V
Reverse current, see Fig 2.	I <sub>R</sub>	V <sub>R</sub> =650V, T <sub>C</sub> =25°C	-	5	60	uA
		V <sub>R</sub> =650V, T <sub>C</sub> =175°C	-	12	-	-
Total capacitive charge, see Fig 6.	Q <sub>C</sub>	V <sub>R</sub> =400V,	-	30	-	nC
Total capacitance, See Fig 5.	C	V <sub>R</sub> =1V, f=1MHZ	-	455	-	pF
		V <sub>R</sub> =200V, f=1MHZ	-	57	-	pF
		V <sub>R</sub> =400V, f=1MHZ	-	56	-	pF
Capacitance Stored Energy, See Fig 7.	E <sub>C</sub>	V <sub>R</sub> =400V	-	4.8	-	uJ



## TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. Forward Characteristics

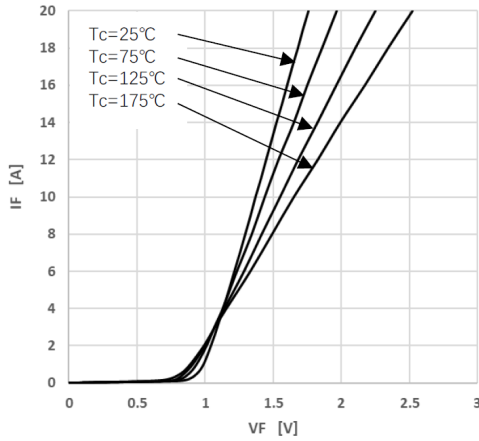


Fig 2. Reverse Characteristics

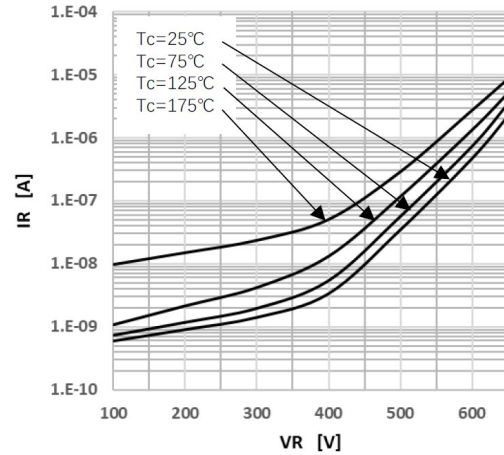


Fig 3. Peak Forward Current Derating

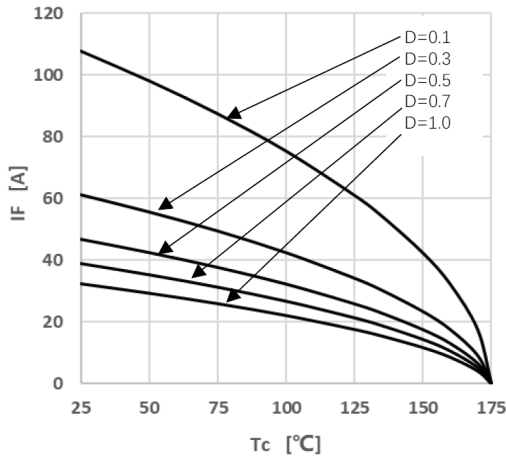


Fig 4. Power Dissipation

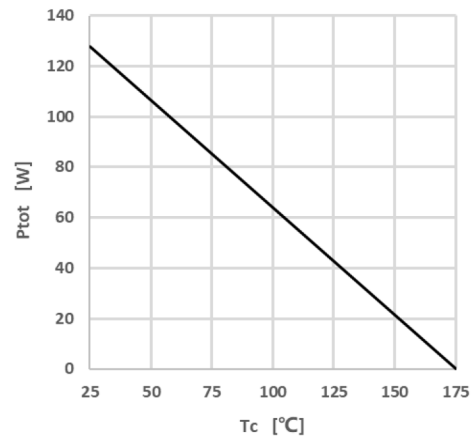


Fig 5. Capacitance vs. Reverse Voltage

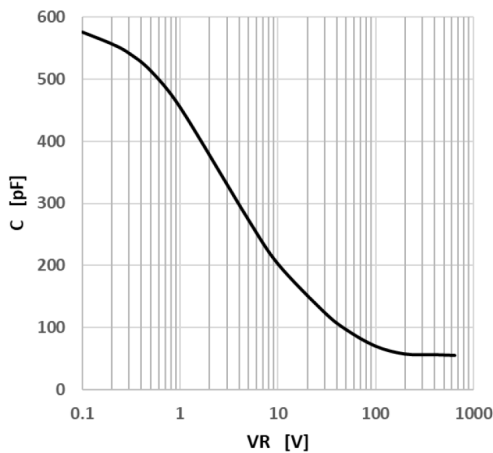


Fig 6. Capacitance Charge vs. Reverse Voltage

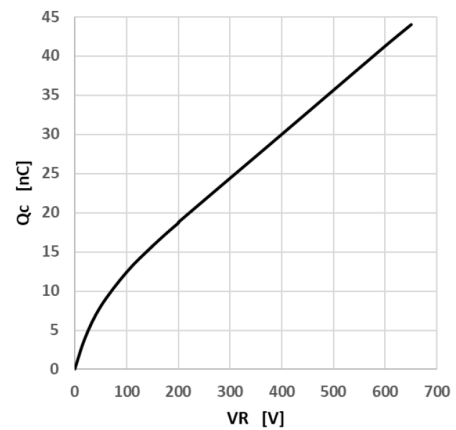




Fig 7. Capacitance Stored Energy

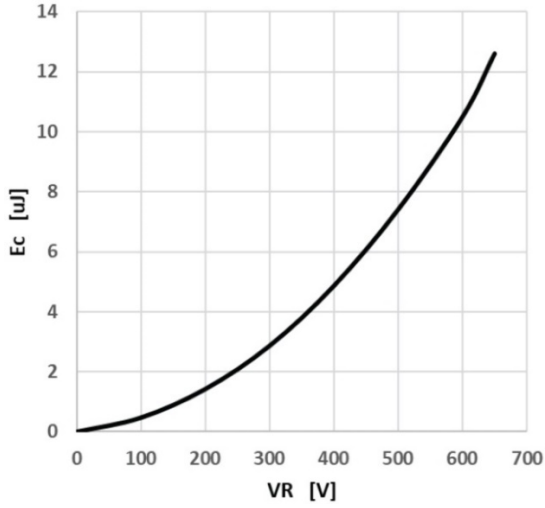
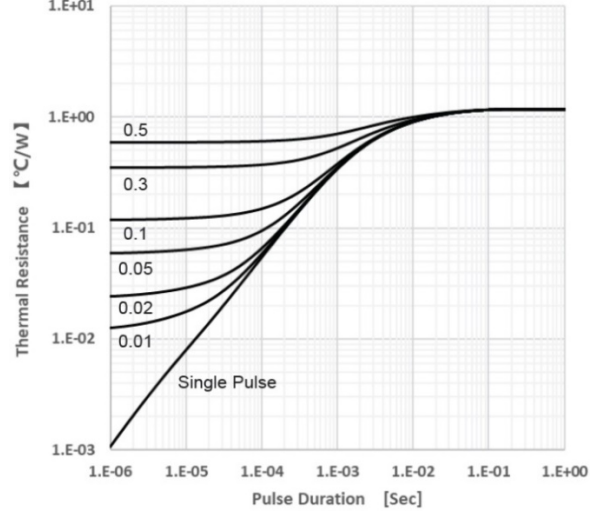


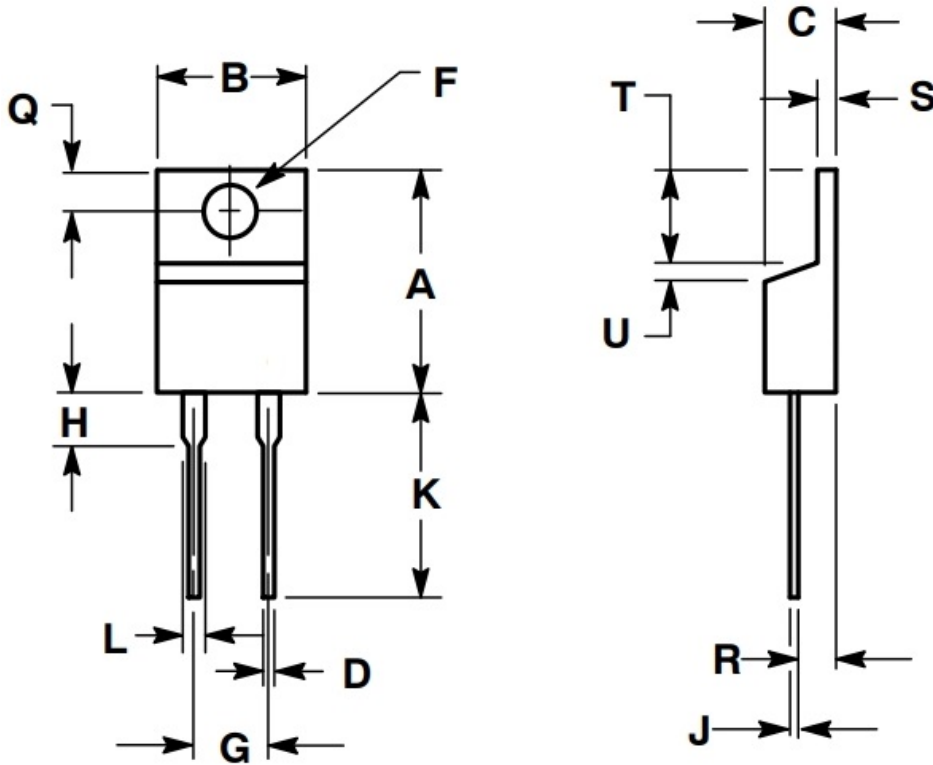
Fig 8. Transient Thermal Impedance





**PACKAGE INFORMATION**

Dimension in TO-220-2 (Unit: mm)



Symbol	Min.	Normal	Max.
A	4.44	4.56	4.65
A1	1.14	1.27	1.39
A2	2.54	2.60	2.79
b	0.69	0.85	0.94
b1	0.38	0.83	0.97
b2	1.20	1.33	1.45
b3	1.20	1.33	0.56
c	0.36	0.50	0.56
c1	0.36	0.48	15.32
D	14.95	15.25	8.89
D1	8.50	8.75	13.30

Symbol	Min.	Normal	Max.
D2	12.20	12.85	13.30
E	10.11	10.18	10.40
E1	8.25	8.57	8.89
e	2.41	2.54	2.67
e1	4.95	5.08	5.20
H1	6.09	6.20	6.40
L	13.52	13.60	14.00
L1	3.56	3.60	3.80
L2	0	-	0.35
ΦP	3.70	3.80	3.91
Q	2.62	2.80	2.87
R			0.20



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